

# BFG93A; BFG93A/X

# **NPN 6 GHz wideband transistors**

Rev. 05 — 26 November 2007

**Product data sheet** 

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### **NPN 6 GHz wideband transistors**

# BFG93A; BFG93A/X

#### **FEATURES**

- High power gain
- Low noise figure
- Gold metallization ensures excellent reliability.

### **APPLICATIONS**

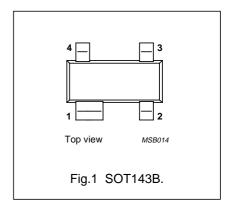
Wideband applications in the UHF and microwave range.

#### **DESCRIPTION**

NPN transistor in a 4-pin, dual-emitter SOT143B plastic package.

#### **PINNING**

PIN	DESCRIPTION
BFG93	A
1	collector
2	base
3	emitter
4	emitter
BFG93	A/X
1	collector
2	emitter
3	base
4	emitter



#### MARKING

TYPE NUMBER	CODE
BFG93A	R8%
BFG93A/X	%MX

#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	_	_	15	V
V <sub>CEO</sub>	collector-emitter voltage	open base	_	_	12	V
Ic	collector current (DC)		_	_	35	mA
P <sub>tot</sub>	total power dissipation	T <sub>s</sub> ≤ 85 °C	_	_	300	mW
C <sub>re</sub>	feedback capacitance	I <sub>C</sub> = i <sub>c</sub> = 0; V <sub>CB</sub> = 5 V; f = 1 MHz	_	0.6	_	pF
f <sub>T</sub>	transition frequency	I <sub>C</sub> = 30 mA; V <sub>CE</sub> = 5 V; f = 500 MHz	4.5	6	_	GHz
G <sub>UM</sub>	maximum unilateral power gain	$I_C$ = 30 mA; $V_{CE}$ = 8 V; $T_{amb}$ = 25 °C; $f$ = 1 GHz	_	16	_	dB
		$I_C$ = 30 mA; $V_{CE}$ = 8 V; $T_{amb}$ = 25 °C; $f$ = 2 GHz	_	10	_	dB
F	noise figure	$\Gamma_{\text{s}} = \Gamma_{\text{opt}}$ ; $I_{\text{C}} = 5$ mA; $V_{\text{CE}} = 8$ V; $T_{\text{amb}} = 25$ °C; $f = 1$ GHz	_	1.7	_	dB

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#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	_	15	V
$V_{CEO}$	collector-emitter voltage	open base	_	12	V
$V_{EBO}$	emitter-base voltage	open collector	_	2	V
$I_{C}$	collector current (DC)		_	35	mA
P <sub>tot</sub>	total power dissipation	T <sub>s</sub> ≤ 85 °C; note 1	_	300	mW
T <sub>stg</sub>	storage temperature range		-65	+150	°C
T <sub>j</sub>	junction operating temperature		_	175	°C

#### Note

1.  $T_s$  is the temperature at the soldering point of the collector pin.

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-s</sub>	thermal resistance from junction to soldering point	note 1	290	K/W

#### Note

1. T<sub>s</sub> is the temperature at the soldering point of the collector pin.

#### **CHARACTERISTICS**

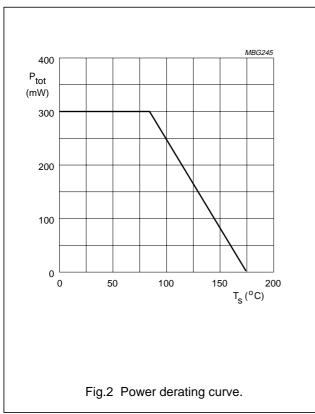
 $T_i = 25$  °C unless otherwise specified.

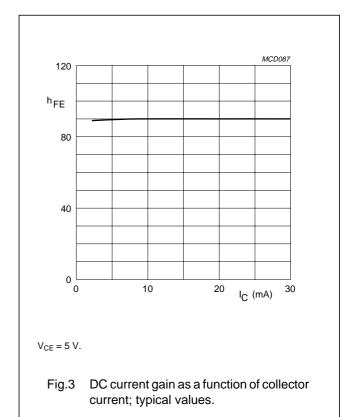
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector leakage current	I <sub>E</sub> = 0; V <sub>CB</sub> = 5 V	_	_	50	nA
h <sub>FE</sub>	DC current gain	$I_C = 30 \text{ mA}; V_{CE} = 5 \text{ V}$	40	90	_	
C <sub>c</sub>	collector capacitance	$I_E = i_e = 0$ ; $V_{CB} = 5 \text{ V}$ ; $f = 1 \text{ MHz}$	_	0.9	_	pF
C <sub>e</sub>	emitter capacitance	$I_C = i_C = 0$ ; $V_{EB} = 5 \text{ V}$ ; $f = 1 \text{ MHz}$	_	1.9	_	pF
$C_{re}$	feedback capacitance	$I_C = i_c = 0$ ; $V_{CB} = 5 \text{ V}$ ; $f = 1 \text{ MHz}$	_	0.6	_	pF
f <sub>T</sub>	transition frequency	$I_C = 30 \text{ mA}; V_{CE} = 5 \text{ V}; f = 500 \text{ MHz}$	4.5	6	_	GHz
G <sub>UM</sub>	maximum unilateral power gain; note 1	$I_C$ = 30 mA; $V_{CE}$ = 8 V; $T_{amb}$ = 25 °C; $f$ = 1 GHz	_	16	_	dB
		$I_C$ = 30 mA; $V_{CE}$ = 8 V; $T_{amb}$ = 25 °C; $f$ = 2 GHz	_	10	_	dB
F	noise figure	$\Gamma_{\text{S}} = \Gamma_{\text{opt}}$ ; $I_{\text{C}} = 5$ mA; $V_{\text{CE}} = 8$ V; $T_{\text{amb}} = 25$ °C; $f = 1$ GHz	_	1.7	_	dB
		$\begin{split} \Gamma_{\text{S}} &= \Gamma_{\text{opt}}; \ I_{\text{C}} = 5 \ \text{mA}; \ V_{\text{CE}} = 8 \ \text{V}; \\ T_{\text{amb}} &= 25 \ ^{\circ}\text{C}; \ f = 2 \ \text{GHz} \end{split}$	_	2.3	_	dB

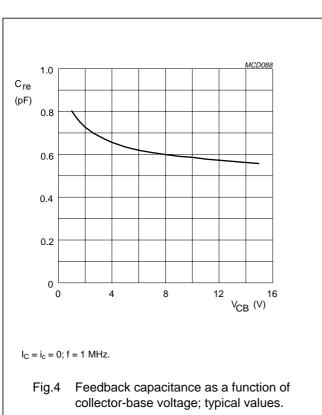
Note

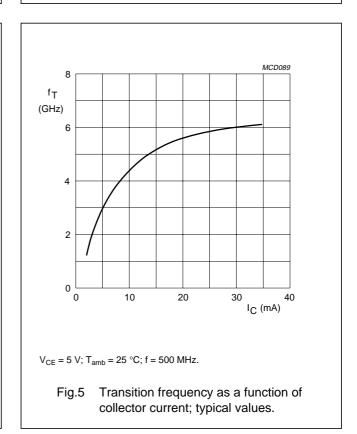
1.  $G_{UM}$  is the maximum unilateral power gain, assuming  $S_{12}$  is zero and  $G_{UM} = 10 \log \frac{|S_{21}|^2}{(1-|S_{11}|^2)(1-|S_{22}|^2)}$  dB.

### NPN 6 GHz wideband transistors









### NPN 6 GHz wideband transistors

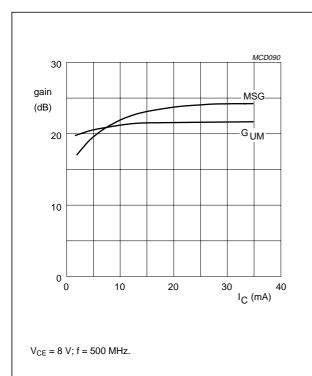
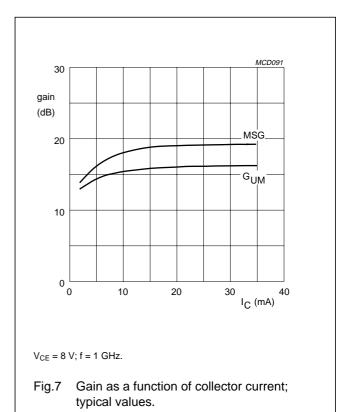
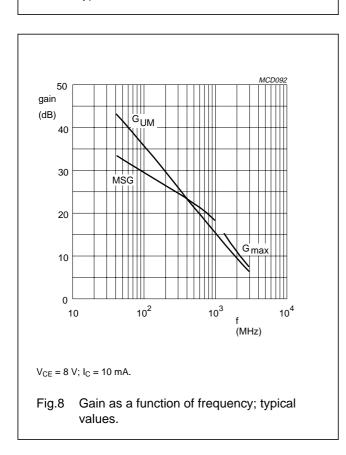
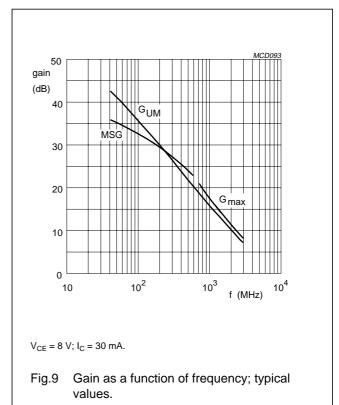


Fig.6 Gain as a function of collector current; typical values.







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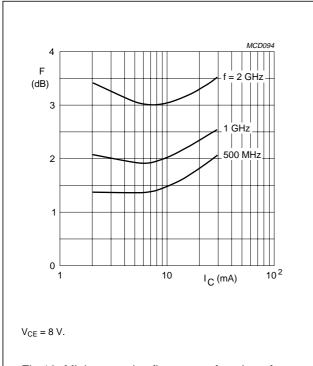
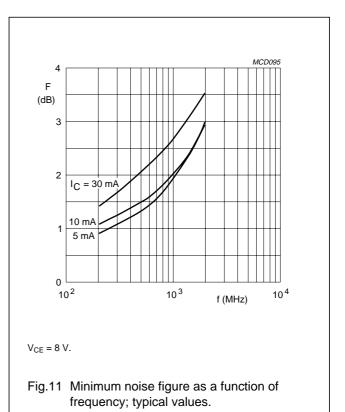
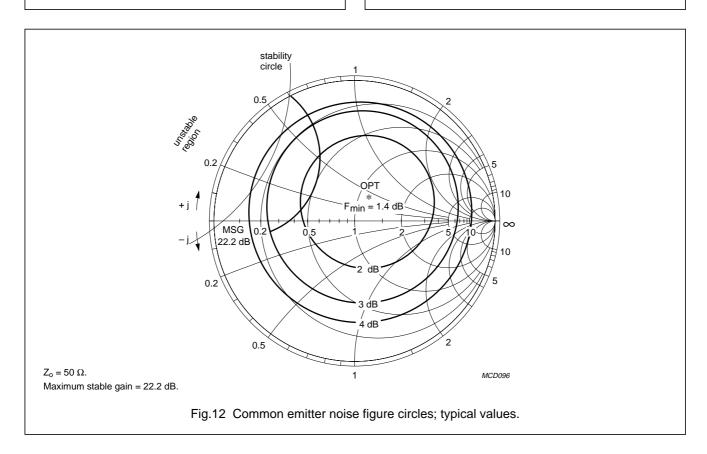
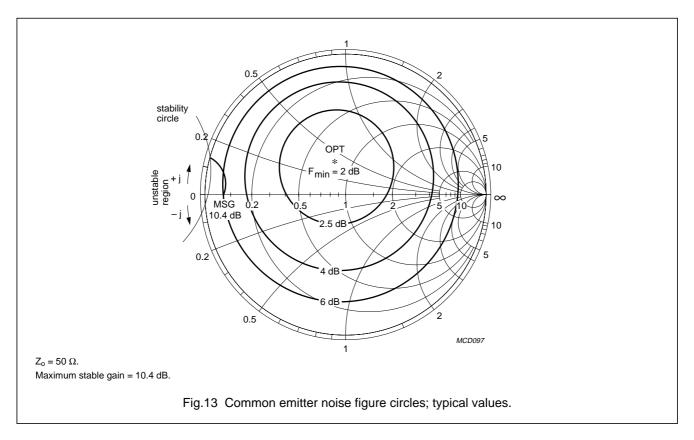


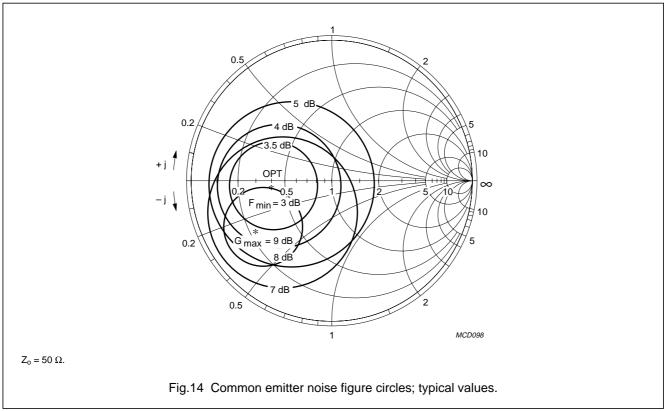
Fig.10 Minimum noise figure as a function of collector current; typical values.

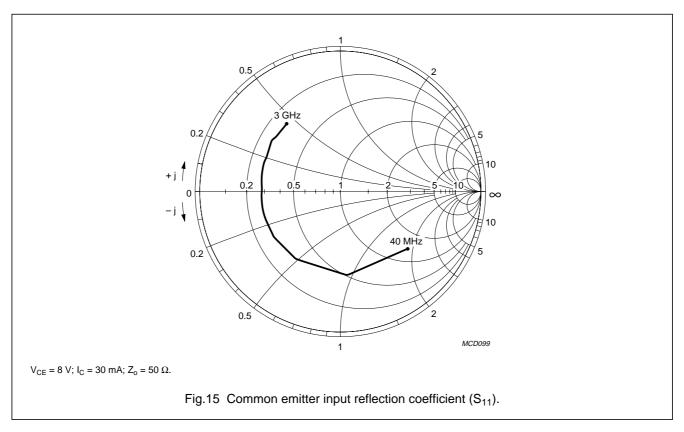


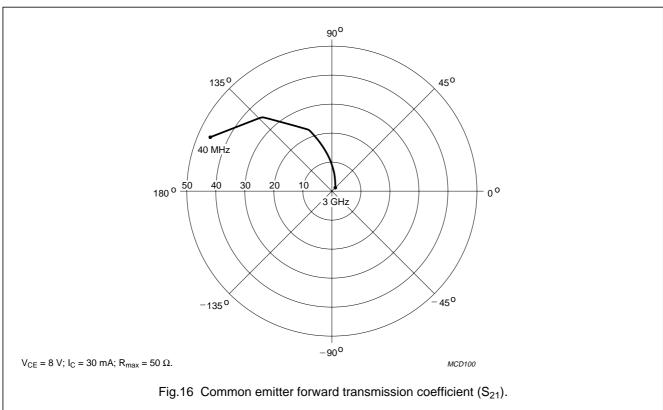


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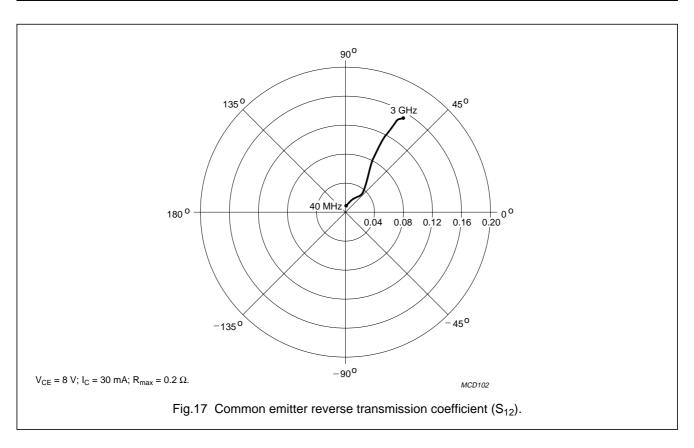


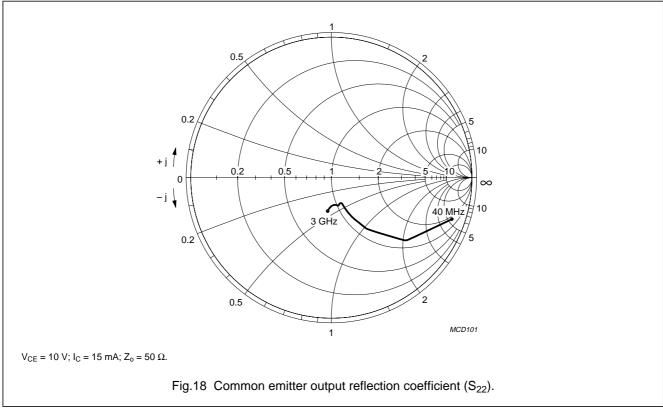






# NPN 6 GHz wideband transistors





### NPN 6 GHz wideband transistors

BFG93A; BFG93A/X

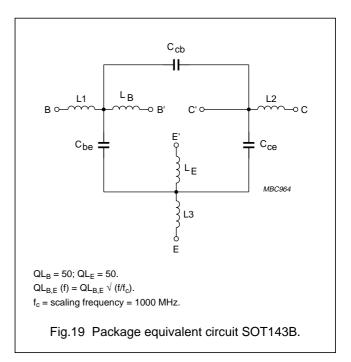
### SPICE parameters for BFR91A(/X) die

SEQUENCE No.	PARAMETER	VALUE	UNIT
1	IS	1.328	fA
2	BF		_
3	NF	1.000	_
4	VAF	51.90	V
5	IKF	8.155	Α
6	ISE	13.90	fA
7	NE	15.12	_
8	BR	17.69	_
9	NR	994.0	m
10	VAR	3.280	V
11	IKR	10.00	Α
12	ISC	1.043	аА
13	NC	1.189	_
14	RB	10.00	Ω
15	IRB	1.000	μΑ
16	RBM	10.00	Ω
17	RE	763.6	mΩ
18	RC	9.000	Ω
19 (note 1)	XTB	0.000	_
20 (note 1)	EG	1.110	EV
21 (note 1)	XTI	3.000	_
22	CJE	2.032	pF
23	VJE	600.0	mV
24	MJE	290.0	m
25	TF	6.557	ps
26	XTF	38.97	_
27	VTF	10.93	V
28	ITF	521.0	mA
29	PTF	0.000	deg
30	CJC	1.003	pF
31	VJC	340.8	mV
32	MJC	194.2	m
33	XCJC	120.0	m
34	TR	3.073	ns
35 (note 1)	CJS	0.000	F

SEQUENCE No.	PARAMETER	VALUE	UNIT
36 (note 1)	VJS	750.0	mV
37 (note 1)	MJS	0.000	_
38	FC	800.0	m

#### Note

1. These parameters have not been extracted, the default values are shown.



### List of components (see Fig.19)

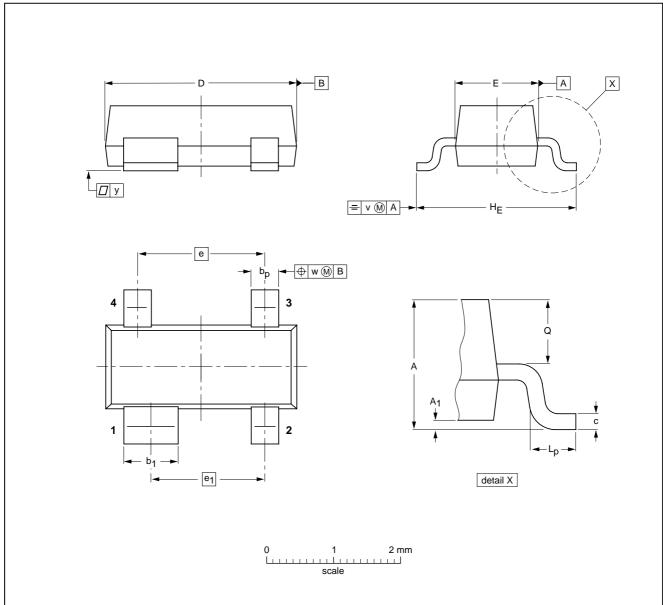
DESIGNATION	VALUE	UNIT
C <sub>be</sub>	84	fF
C <sub>cb</sub>	17	fF
C <sub>ce</sub>	191	fF
L1	0.12	nH
L2	0.21	nH
L3	0.06	nH
L <sub>B</sub>	0.95	nH
L <sub>E</sub>	0.40	nH

BFG93A; BFG93A/X

### **PACKAGE OUTLINE**

### Plastic surface mounted package; 4 leads

SOT143B



#### **DIMENSIONS** (mm are the original dimensions)

UNIT	A	A <sub>1</sub> max	bp	b <sub>1</sub>	С	D	E	е	e <sub>1</sub>	HE	L <sub>p</sub>	Q	v	w	у
mm	1.1 0.9	0.1	0.48 0.38	0.88 0.78	0.15 0.09	3.0 2.8	1.4 1.2	1.9	1.7	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1	0.1

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT143B						97-02-28

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#### **Data sheet status**

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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# **Revision history**

### **Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
BFG93A_X_N_5	20071126	Product data sheet	-	BFG93A_X_4
Modifications:	<ul> <li>Marking table</li> </ul>	e on page 2; changed code		
BFG93A_X_4 (9397 750 04351)	19980923	Product specification	-	BFG93SERIES_3
BFG93SERIES_3	19950925	Product specification	-	BFG93SERIES_2
BFG93SERIES_2	-	Product specification	-	BFG93_SERIES_1
BFG93_SERIES_1	-	-	-	-

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